





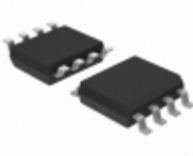
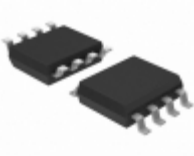

	<p><b>SI8417DB-T2-E1</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI8417DB-T2-E1</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 12V 14.5A 2X2 6MFP</p> <p><b>Datenblätter:</b>  <a href="#">SI8417DB-T2-E1.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 219500 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI8417DB-T2-E1
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 12V 14.5A 2X2 6MFP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	219500 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-MICRO FOOT™
Supplier Device-Gehäuse	6-Micro Foot™
Verlustleistung (max)	2.9W (Ta), 6.57W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	14.5A (Tc)
Rds On (Max) @ Id, Vgs	21 mOhm @ 1A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	57nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	2220pF @ 6V
Verpackung	Tape & Reel (TR)



















































SI8417DB-T2-E1 ist neu im Original, Suche SI8417DB-T2-E1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI8417DB-T2-E1 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI8417DB-T2-E1: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI8420-B-IS</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV GEN PURP 8SOIC</p>	 <p><b>SI8420</b> SILICON SI8420 SILICON</p>	 <p><b>SI8416DB-T2-E1</b> Vishay / Siliconix MOSFET N-CH 8V 16A MICRO</p>	 <p><b>SI8416DB-T2-E1</b> Electro-Films (EFI) / Vishay MOSFET N-CH 8V 16A MICRO</p>
 <p><b>SI8420AB</b> SILICON SI8420AB SILICON</p>	 <p><b>SI8420-A-IS</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV GEN PURP 8SOIC</p>	 <p><b>SI8420-C-IS</b> Energy Micro (Silicon Labs) DGTL ISO 2.5KV GEN PURP 8SOIC</p>	 <p><b>SI8416DB-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 8V 16A MICRO</p>

heiße Teile

Mehr

 SI8402DB-T1	 SI8402DB-T1-E1	 SI8402DB-T1-E1	 SI8402DB-T1-E1.	 SI8402DB-T1-E3
 SI8404DB-T1-E1	 SI8404DB-T1-E1	 SI8405DB	 SI8405DB-T1	 SI8405DB-T1-E1
 SI8405DB-T1-E1	 SI8405DB-T1-E3	 SI8405DB-T1-E3	 SI8409DB-T1	 SI8409DB-T1-E1
 SI8409DB-T1-E1	 SI8410AB	 SI8410BB-D-ISR	 SI8410BB-I-DS	 SI8413DB-T1-E1
 SI8413DB-T1-E1	 SI8415DB-T1	 SI8415DB-T1-E1	 SI8415DB-T1-E1	 SI8417DB-T2-E1
 SI8420BB	 SI8420BB-D-IS	 SI8421AB-D-ISR	 SI8422AB-D-ISR	 SI8422BD
 SI8424DB-T1-E1	 SI8424DB-T1-E1	 SI8425DB-T1-E1	 SI8425DB-T1-E1	 SI8429DB-T1-E1
 SI8429DB-T1-E1	 SI8430-A-IS	 SI8430-BIS	 SI8430-C-IS	 SI8430AB-D-IS
 SI8430AB-D-ISR	 SI8430BB-C-IS	 SI8430BB-D-IS	 SI8431-A-IS	 SI8431-BIS
 SI8431-C-IS	 SI8431AB-C-IS	 SI8431AB-D-IS	 SI8431AB-D-IS1R	 SI8431BB-C-IS

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited